





TPS53353

TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Ecomode™

1 Features

- New product available: TPS548B28 16-V, 20-A synchronous-buck converter with remote sense
- Conversion input voltage range: 1.5 V to 15 V
- VDD input voltage range: 4.5 V to 25 V
- 92% efficiency from 12 V to 1.5 V at 20 A
- Output voltage range: 0.6 V to 5.5 V
- 5-V LDO output
- Supports single-rail input
- Integrated power MOSFETs with 20 A of continuous output current
- Auto-skip Eco-mode™ for light-load efficiency
- < 10-uA shutdown current
- D-CAP™ mode with fast transient response
- Selectable switching frequency from 250 kHz to 1 MHz with external resistor
- Selectable auto-skip or PWM-only operation
- Built-in 1% 0.6-V reference
- 0.7-ms, 1.4-ms, 2.8-ms, and 5.6-ms selectable internal voltage servo soft start
- Integrated boost switch
- Precharged start-up capability
- Adjustable overcurrent limit with thermal compensation
- Overvoltage, undervoltage, UVLO, and overtemperature protection
- Supports all ceramic output capacitors
- Open-drain power-good indication
- Incorporates NexFET™ power block technology
- 22-pin QFN package with PowerPAD™
- For SWIFT™ power products documentation, see http://www.ti.com/swift

2 Applications

- Enterprise rack Servers and storage
- Wired networking switches and routers
- ASIC, SoC, FPGA, DSP core, and I/O voltage

3 Description

TPS53353 is a D-CAP™ mode, 20-A synchronous switcher with integrated MOSFETs. It is designed for ease of use, low external component count, and space-conscious power systems.

This device features 5.5-m Ω / 2.2-m Ω integrated MOSFETs, accurate 1%, 0.6-V reference, and integrated boost switch. A sample of competitive features include: a conversion input voltage range from 1.5 V to 15 V, very low external component count, D-CAP™ mode control for super fast transient, auto-skip mode operation, internal soft-start control, selectable frequency, and no need for compensation.

The conversion input voltage ranges from 1.5 V to 15 V, the supply voltage range is from 4.5 V to 25 V, and the output voltage range is from 0.6 V to 5.5 V.

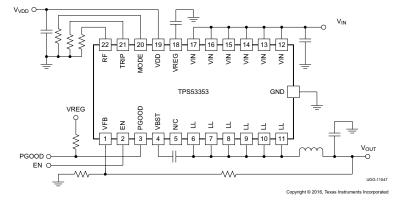
The device is available in 5-mm × 6-mm, 22-pin QFN package and is specified from -40°C to 85°C.

The TPS548B28 is a newer 20A device designed for data center applications with a smaller, Pb-free package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TPS53353	LSON-CLIP (22)	6.00 mm × 5.00 mm		

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Application

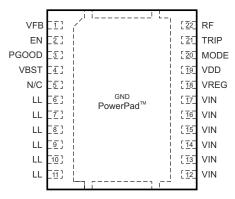


Table of Contents

NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	2 Applications		17
3 Description. 1 8.1 Application Information. 20 4 Revision History 2 8.2 Typical Applications 20 5 Pin Configuration and Functions. 3 9 Power Supply Recommendations. 20 6 Specifications. 4 10 Layout. 30 6.1 Absolute Maximum Ratings ⁽¹⁾ . 4 10.1 Layout Guidelines. 30 6.2 ESD Ratings. 4 10.2 Layout Example. 31 6.3 Recommended Operating Conditions. 4 11 Device and Documentation Support. 32 6.6 Typical Characteristics. 5 11.2 Receiving Notification of Documentation Updates. 32 6.6 Typical Characteristics. 5 11.2 Receiving Notification of Documentation Updates. 32 6.6 Typical Characteristics. 7 11.3 Support Resources. 32 7.1 Overview. 13 11.4 Trademarks. 32 7.1 Overview. 13 11.5 Electrostate Discharge Caution. 32 7.3 Feature Description. 14 4 Revision History NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Page 4 Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package. 1 1 Updated the numbering format for tables, figures, and cross-references throughout the document. 1 2 Added TPS548B28 information to Section 3 as a newer 20A device in a smaller package. 1 3 Changed the EN waveform and overall delay time on Figure 7-1 and updated and moved the Figure 7-1 note into the Section 7.3 Lascription 14 4 Added Egyation 19 and supporting information. 25 6 MODE and RF pins updated in Figure 10-1 31 Changes from Revision B (February 2015) to Revision C (February 2016) Page C Changed the datasheet Title From: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™": "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™": "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS533535 High-Efficiency 20		1 8 Application and Implementation	ı20
4 Revision History 2 8 3 2 Typical Applications 3 9 Power Supply Recommendations 20 6 Specifications 4 10 Layout 30 6 2 ESD Ratings 4 10 1 Layout Guidelines 30 6 2 ESD Ratings 4 10 1 Layout Guidelines 30 6 2 ESD Ratings 4 10 1 Layout Example 30 10 2 Layout Example 31 11 Device and Documentation Support 32 6 15 Electrical Characteristics 30 10 2 Layout Example 31 11 Device and Documentation Support 32 6 15 Electrical Characteristics 5 11 1 Device Support 11 2 Receiving Notification of Documentation Updates 32 7 Detailed Description 31 11 1 Face Provides Support 32 7 11 3 Support Resources 32 7 2 Functional Block Diagram 13 11 6 Glossary 32 7 2 Functional Block Diagram 13 11.6 Glossary 32 7 3 Feature Description 44 Revision History NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Page 4 Added TPS548B28 information to Section 1 as a newer 204 device in a smaller package 1 Updated the numbering format for tables, figures, and cross-references throughout the document 1 Added TPS548B28 information to Section 3 as a newer 204 device in a smaller package 1 Changed the EN waveform and overall delay time on Figure 7-1 and updated and moved the Figure 7-1 note into the Section 7.3.1 description 1 Added BST Resistor Selection to Section 8.2.2.2.1 2 Added Equation 19 and supporting information 2 MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) to Revision C (February 2016) Page • Changed the datasheet Title From: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode 1 and Added Seption 1 and Supporting information section, Device Punctional Modes, Application and Implementation section, Packaging, and Orderable Information section. • Added Fin Configuration and Functions section, ESD Ratings table, Feature Description section, Layout Section, 10 Page • Changed Conversion input voltage from 13 V* to 1.5 V*. 1 Changes from Revision Original (August 2011) to Revis			
6 Specifications 4 10 Layout	4 Revision History		
6 Specifications 4 10 Layout	5 Pin Configuration and Functions		
6.1 Absolute Maximum Ratings ⁽¹⁾ 4 10.1 Layout Example. 30 6.2 ESD Ratings. 4 10.2 Layout Example. 31 6.3 Recommended Operating Conditions. 4 11 Device and Documentation Support. 32 6.4 Thermal Information. 5 11.1 Device Support. 32 6.5 Electrical Characteristics	6 Specifications	4 10 Layout	
6.2 ESD Ratings. 4 110.2 Layout Example. 31 6.3 Recommended Operating Conditions. 4 11 Device and Documentation Support. 32 6.6 Thermal Information. 5 11.1 Device Support. 32 6.6 Teleptorical Characteristics. 5 11.2 Receiving Notification of Documentation Updates. 32 6.6 Typical Characteristics. 7 11.3 Support Resources. 32 7 Detailed Description. 13 11.5 Electrostatic Discharge Caution. 32 7.1 Overview. 13 11.5 Electrostatic Discharge Caution. 32 7.2 Functional Block Diagram. 13 11.5 Electrostatic Discharge Caution. 32 7.3 Feature Description. 14 4 Revision History NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Page - Added TPS548828 information to Section 3 as a newer 20A device in a smaller package. 1 - Updated the numbering format for tables, figures, and cross-references throughout the document. 1 - Added TPS548828 information to Section 3 as a newer 20A device in a smaller package. 1 - Changed the EN waveform and overall delay time on Figure 7-1 and updated and moved the Figure 7-1 note into the Section 7.3 description 14 - Added BST Resistor Selection to Section 8.2.2.2.1 24 - Added Equation 19 and supporting information. 25 - MODE and RF pins updated in Figure 10-1 35 Changes from Revision B (February 2015) to Revision C (February 2016) Page - Changed the datasheat Title From: TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™ To: "Teypel Product Documentation." 1 Changes from Revision Original (August 2011)	6.1 Absolute Maximum Ratings ⁽¹⁾	4 10.1 Layout Guidelines	30
6.4 Thermal Information			31
6.5 Electrical Characteristics	6.3 Recommended Operating Conditions	4 11 Device and Documentation Su	pport32
6.6 Typical Characteristics. 7 7 Detailed Description	6.4 Thermal Information	5 11.1 Device Support	32
7 Detailed Description	6.5 Electrical Characteristics	5 11.2 Receiving Notification of Doc	cumentation Updates 32
7.1 Overview 13 11.5 Electrostatic Discharge Caution 32 7.2 Functional Block Diagram 13 11.6 Glossary 32 7.3 Feature Description 14 11.6 Glossary 32 7.3 Feature Description 15 7.3 Feature Description 15 7.3 Feature Description 15 7.3 Feature Description 16 7.3 Feature Description 16 7.3 Feature Description 17 7.3 Feature Description 17 7.3 Feature Description 17 7.3 Feature Description 18 7.3 Feature Description 19 7.5 Feature Description Section 19	6.6 Typical Characteristics	7 11.3 Support Resources	32
7.2 Functional Block Diagram	7 Detailed Description	13 11.4 Trademarks	32
4 Revision History NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Page Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	7.1 Overview	13 11.5 Electrostatic Discharge Cauti	ion32
4 Revision History NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) • Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	7.2 Functional Block Diagram	13 11.6 Glossary	32
NOTE: Page numbers for previous revisions may differ from page numbers in the current version. Changes from Revision C (December 2016) to Revision D (April 2021) Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	7.3 Feature Description	14	
 Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	4 Revision History NOTE: Page numbers for previous revisions m	ay differ from page numbers in the current v	ersion.
 Added TPS548B28 information to Section 1 as a newer 20A device in a smaller package	Changes from Revision C (December 2016)	to Revision D (April 2021)	Page
 Updated the numbering format for tables, figures, and cross-references throughout the document. Added TPS548B28 information to Section 3 as a newer 20A device in a smaller package. Changed the EN waveform and overall delay time on Figure 7-1 and updated and moved the Figure 7-1 note into the Section 7.3.1 description. Added BST Resistor Selection to Section 8.2.2.2.1 Added Equation 19 and supporting information. MODE and RF pins updated in Figure 10-1. MODE and RF pins updated in Figure 10-1. Changes from Revision B (February 2015) to Revision C (February 2016) Page Changed the datasheet Title From: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™" To: "TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Ecomode™ To: "For SWIFT™ Power Product Documentation" Added Section 1: "For SWIFT™ Power Product Documentation" Changes from Revision A (April 2012) to Revision B (February 2015) Page Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section Changes from Revision Original (August 2011) to Revision A (April 2012) Page Changed conversion input voltage from "3 V" to "1.5 V" Changed VIN input voltage range minimum from "3 V" to "1.5 V" in Section 6.3 Changed VIN (main supply) input voltage range minimum from "3 V" to "1.5 V" in Section 6.3 Added note to the Section 7.3 Changed "ripple injection capacitor" to "ripple injection resistor" in the last bullet of the Layout Guidelines 			
Added TPS548B28 information to Section 3 as a newer 20A device in a smaller package			
 Changed the EN waveform and overall delay time on Figure 7-1 and updated and moved the Figure 7-1 note into the Section 7.3.1 description			
into the Section 7.3.1 description			
Added BST Resistor Selection to Section 8.2.2.2.1	•	• •	•
 Added Equation 19 and supporting information	Into the Section 7.3.1 description		
 MODE and RF pins updated in Figure 10-1			
Changes from Revision B (February 2015) to Revision C (February 2016) • Changed the datasheet Title From: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™" To: "TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Ecomode™"	• Added BST Resistor Selection to Section 8	2.2.2.1	24
 Changed the datasheet Title From: "TPS53353 High-Efficiency 20-A Synchronous Buck Converter With Ecomode™" To: "TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Eco-mode™"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa 	2.2.2.1on	24 25
mode ™ To: "TPS53353 High-Efficiency 20-A Synchronous Buck SWIFT™ Converter With Eco-mode ™	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa 	2.2.2.1on	24 25
 Added Section 1: "For SWIFT™ Power Product Documentation"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 	2.2.2.1 on	24 25 31
 Added Section 1: "For SWIFT™ Power Product Documentation"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1	o Revision C (February 2016)	24 25 31
 Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section Changes from Revision Original (August 2011) to Revision A (April 2012) Page Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) to Changed the datasheet Title From: "TPS53 	D Revision C (February 2016) 353 High-Efficiency 20-A Synchronous Buck	
 Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section Changes from Revision Original (August 2011) to Revision A (April 2012) Page Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 	Property 2016) Revision C (February 2016) Residential Control Contr	24 25 31 Page Converter With Eco- Vith Eco-mode™"1
Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro 	on	24 25 31
section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Re 	Proceedings of the Process of the P	25 31 Page Converter With Eco- Vith Eco-mode™" 1 1
Changes from Revision Original (August 2011) to Revision A (April 2012) Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Re Added Pin Configuration and Functions sections 	Property 2016) Revision C (February 2016) Revision C (February 2016) Revision B (February 2015) Revision B (February 2015) Revision B (February 2015) Revision B (February 2015)	Page Converter With Eco- Vith Eco-mode™" 1 Page r section, Device
Changes from Revision Original (August 2011) to Revision A (April 2012) Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference Added Pin Configuration and Functions sectional Modes, Application and Implementation 	Property 2016) Revision C (February 2016) Revision C (February 2016) Revision B (February 2015)	Page Converter With Eco- Vith Eco-mode™" 1 Page n section, Device ations section, Layout
 Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference Added Pin Configuration and Functions section, Device and Documentation Suppose 	ORevision C (February 2016) Bis 3 High-Efficiency 20-A Synchronous Buck A Synchronous Buck SWIFT™ Converter William B (February 2015) Sion, ESD Ratings table, Feature Description Intation section, Power Supply Recommendate Section, and Mechanical, Packaging, and Consequence of Section of Secti	Page Converter With Eco- Vith Eco-mode TM" 1 Page a section, Device ations section, Layout Drderable Information
 Changed conversion input voltage from "3 V" to "1.5 V"	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference Added Pin Configuration and Functions section, Device and Documentation Suppose 	ORevision C (February 2016) Bis 3 High-Efficiency 20-A Synchronous Buck A Synchronous Buck SWIFT™ Converter William B (February 2015) Sion, ESD Ratings table, Feature Description Intation section, Power Supply Recommendate Section, and Mechanical, Packaging, and Consequence of Section of Secti	Page Converter With Eco- Vith Eco-mode TM" 1 Page a section, Device ations section, Layout Drderable Information
 Changed to correct typographical error in THERMAL INFORMATION table	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference and Proceedings of the Added Pin Configuration and Functions section, Device and Documentation Suppose section Changes from Revision Original (August 20 	Property 2016) Revision C (February 2016) Revision C (February 2016) Revision B (February 2015) Revision B (February 2015) Revision B (February 2015) Revision Section, Power Supply Recommendation section, Power Supply Recommendation section, and Mechanical, Packaging, and Commendation and Mechanical and Mec	Page Converter With Eco- Vith Eco-mode™"1 Page a section, Device ations section, Layout Drderable Information1 Page
 Changed to correct typographical error in THERMAL INFORMATION table	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference and Eventuary Power Profession, Device and Documentation Suppose Section Changes from Revision Original (August 20 Changed conversion input voltage from "3" 	Property 2016 Property 2016 Property 2016 Property 2016 Property 2016 Property 2016 Property 2015 Property 2016 P	Page Converter With Eco- Vith Eco-mode ™" 1 Page a section, Device ations section, Layout Drderable Information Page Page
 Changed VIN (main supply) input voltage range minimum from "3 V' to "1.5 V" in Section 6.3	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Pro Changes from Revision A (April 2012) to Reference and Eventuary Power Profession, Device and Documentation Suppose Section Changes from Revision Original (August 20 Changed conversion input voltage from "3" 	Property 2016 Property 2016 Property 2016 Property 2016 Property 2016 Property 2016 Property 2015 Property 2016 P	Page Converter With Eco- Vith Eco-mode ™" 1 Page a section, Device ations section, Layout Drderable Information Page Page
 Changed conversion input voltage range from "3 V" to "1.5" in Section 7.1 Added note to the Section 7.3 Changed "ripple injection capacitor" to "ripple injection resistor" in the last bullet of the Layout Guidelines 	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Proceed of the Configuration and Functions section, Device and Documentation Supposection Changes from Revision Original (August 20 Changed conversion input voltage from "3" Changed VIN input voltage range minimum 	ORevision C (February 2016) B53 High-Efficiency 20-A Synchronous Buck A Synchronous Buck SWIFT™ Converter William B (February 2015) Bion, ESD Ratings table, Feature Description Intation section, Power Supply Recommendate section, and Mechanical, Packaging, and Commendation and Mechanical Packaging and Commendation Section A (April 2012) To The Tebruary 2015	Page Converter With Eco- Vith Eco-mode™" 1 Page a section, Device ations section, Layout Drderable Information Page Page Page 1
 Added note to the Section 7.3	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Proceed of the Configuration A (April 2012) to Reference of the Configuration and Functions seed Functional Modes, Application and Implementation, Device and Documentation Supposection Changes from Revision Original (August 20 Changed conversion input voltage from "3" Changed VIN input voltage range minimum Changed to correct typographical error in T 	on	Page Converter With Eco- Vith Eco-mode™" 1 Page n section, Device ations section, Layout Drderable Information Page Page 1 Page 1 1 1 1
Changed "ripple injection capacitor" to "ripple injection resistor" in the last bullet of the Layout Guidelines	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Proceed Proceeding 1: "For SWIFT™ Power Proceeding 1:	ORevision C (February 2016) So Revision C (February 2016) So High-Efficiency 20-A Synchronous Buck A Synchronous Buck SWIFT™ Converter Water Documentation" Wision B (February 2015) Tion, ESD Ratings table, Feature Description attation section, Power Supply Recommendate section, and Mechanical, Packaging, and Company 11 to Table Trom Table Tro	Page Converter With Eco- Vith Eco-mode™" 1 Page n section, Device ations section, Layout Drderable Information Page Page 1 Page 1 A Page 1 Page 1 Page 1 Page 1 Page 1 Page 1 A Page 1 Page 1
	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Proceed of the Configuration and Functions seed Functional Modes, Application and Implementation, Device and Documentation Supposection Changes from Revision Original (August 20 Changed conversion input voltage from "3" Changed VIN input voltage range minimum Changed VIN (main supply) input voltage range from Changed conversion input voltage range from Changed Cha	ORevision C (February 2016) ORevision C (February 2016) OREVISION C (February 2016) OREVISION C (February 2016) OREVISION C (February 2015) OREVISION B (February 2015) OREVISION B (February 2015) OREVISION C (February 2016) OREVISION C (February 2015) OREVISION C (Fe	Page Converter With Eco- Vith Eco-mode™" 1 Page a section, Device ations section, Layout Drderable Information 1 Page
	 Added BST Resistor Selection to Section 8 Added Equation 19 and supporting informa MODE and RF pins updated in Figure 10-1 Changes from Revision B (February 2015) 1 Changed the datasheet Title From: "TPS53 mode™" To: "TPS53353 High-Efficiency 20 Added Section 1: "For SWIFT™ Power Proceed of the Added Pin Configuration and Functions section, Device and Documentation Supposesction, Device and Documentation Supposesction Changes from Revision Original (August 20 Changed conversion input voltage from "3" Changed VIN input voltage range minimum Changed VIN (main supply) input voltage range from Changed conversion input voltage range from Added note to the Section 7.3 	ORevision C (February 2016) B53 High-Efficiency 20-A Synchronous Buck A Synchronous Buck SWIFT™ Converter William B (February 2015) Bion, ESD Ratings table, Feature Description Intation section, Power Supply Recommendate section, and Mechanical, Packaging, and Communication Testion A (April 2012) To "1.5 V"	Page Converter With Eco- Vith Eco-mode™" 1 Page a section, Device ations section, Layout Drderable Information 1 Page



5 Pin Configuration and Functions



A. N/C = no connection

Figure 5-1. 22-Pins LSON-CLIP DQP Package (Top View)

Table 5-1. Pin Functions

PIN NAME NO.			DESCRIPTION		
		IIPE(')			
EN	2	I	Enable pin.Typical turnon threshold voltage is 1.2 V. Typical turnoff threshold voltage is 0.95 V.		
GND		G	Ground and thermal pad of the device. Use proper number of vias to connect to ground plane.		
	6				
	7				
LL	8	В	Output of converted power. Connect this pin to the output Inductor.		
LL	9	В	Output of converted power. Connect this pin to the output inductor.		
	10				
	11				
MODE	20	I	Soft-start and Skip/CCM selection. Connect a resistor to select soft-start time using Table 7-3. The soft-start time is detected and stored into internal register during start-up.		
N/C	5		No connect.		
PGOOD	3	0	Open drain power good flag. Provides 1-ms start-up delay after VFB falls in specified limits. When VFB goes out of the specified limits PGOOD goes low after a 2-µs delay		
RF	22	I	Switching frequency selection. Connect a resistor to GND or VREG to select switching frequency using Table 7-1. The switching frequency is detected and stored during the startup.		
TRIP	21 I		OCL detection threshold setting pin. I_{TRIP} = 10 μ A at room temperature, 4700 ppm/°C current is sourced and set the OCL trip voltage as follows.		
			$V_{OCL} = V_{TRIP}/32$ $(V_{TRIP} \le 1.2 \text{ V}, V_{OCL} \le 37.5 \text{ mV})$		
VBST	4	Р	Supply input for high-side FET gate driver (boost terminal). Connect capacitor from this pin to LL node. Internally connected to VREG via bootstrap MOSFET switch.		
VDD	19	Р	Controller power supply input. VDD input voltage range is from 4.5 V to 25 V.		
VFB	1	ı	Output feedback input. Connect this pin to Vout through a resistor divider.		
	12				
	13				
VIN	14	P	Conversion power input.The conversion input voltage range is from 1.5 V to 15 V.		
VIIN	15		Conversion power input. The conversion input voltage range is from 1.5 v to 15 v.		
	16				
	17				
VREG	18	Р	5-V low drop out (LDO) output. Supplies the internal analog circuitry and driver circuitry.		

(1) I=Input, O=Output, B=Bidirectional, P=Supply, G=Ground



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

			MIN	MAX	UNIT
	VIN (main supply)	-0.3	25	
	VDD		-0.3	28	
Input voltage range	VBST		-0.3	32	v
	VBST	(with respect to LL)	-0.3	7	
	EN, T	RIP, VFB, RF, MODE	-0.3	7	
		DC	-2	25	
Output valtage renge	LL	Pulse < 20ns, E=5 μJ	-7	27] _V
Output voltage range	PGO	DD, VREG	-0.3	7	
	GND		-0.3	0.3	
Source/Sink current	VBST		50		mA
Operating free-air temper	ature,	Γ _A	-40	85	
Junction temperature, T _J		-40	150	°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds			300		
Storage temperature, T _{stg}			– 55	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Section 6.3* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
	VIN (main supply)	1.5	15	
	VDD	4.5	25	
Input voltage range	VBST	4.5	28	V
	VBST(with respect to LL)	4.5	6.5	
	EN, TRIP, VFB, RF, MODE	-0.1	6.5	
Output voltage range	LL	-1	22	V
	PGOOD, VREG	-0.1	6.5	v
Junction temperature range, T _J		-40	125	°C

Product Folder Links: TPS53353



6.4 Thermal Information

		TPS53353	
	THERMAL METRIC ⁽¹⁾	DQP (LSON-CLIP)	UNIT
		22 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	27.2	
θ_{JCtop}	Junction-to-case (top) thermal resistance	17.1	
θ_{JB}	Junction-to-board thermal resistance	5.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.8	C/VV
Ψ_{JB}	Junction-to-board characterization parameter	5.8	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	1.2	

⁽¹⁾ For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

Over recommended free-air temperature range, V_{VDD}= 12 V (unless otherwise noted)

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY C	URRENT			<u>'</u>	'	
V _{VIN}	VIN pin power conversion input voltage		1.5		15	V
V_{VDD}	Supply input voltage		4.5		25	V
I _{VIN(leak)}	VIN pin leakage current	V _{EN} = 0 V			1	μΑ
I _{VDD}	VDD supply current	T _A = 25°C, No load, V _{EN} = 5 V, V _{VFB} = 0.630 V		420	590	μA
I _{VDDSDN}	VDD shutdown current	T _A = 25°C, No load, V _{EN} = 0 V			10	μΑ
INTERNAL	REFERENCE VOLTAGE					
V _{VFB}	VFB regulation voltage	CCM condition ⁽¹⁾		0.6		V
		T _A = 25°C	0.597	0.6	0.603	
V_{VFB}	VFB regulation voltage	0°C ≤ T _A ≤ 85°C	0.5952	0.6	0.6048	V
		-40°C ≤ T _A ≤ 85°C	0.594	0.6	0.606	
I _{VFB}	VFB input current	V _{VFB} = 0.630 V, T _A = 25°C		0.01	0.2	μΑ
LDO OUTF	TUT					
V _{VREG}	LDO output voltage	0 mA ≤ I _{VREG} ≤ 30 mA	4.77	5	5.36	V
I _{VREG}	LDO output current ⁽¹⁾	Maximum current allowed from LDO			30	mA
V _{DO}	Low drop out voltage	V _{VDD} = 4.5 V, I _{VREG} = 30 mA			230	mV
BOOT STE	RAP SWITCH					
V _{FBST}	Forward voltage	$V_{VREG-VBST}$, I_F = 10 mA, T_A = 25°C		0.1	0.2	V
I _{VBSTLK}	VBST leakage current	V _{VBST} = 23 V, V _{SW} = 17 V, T _A = 25°C		0.01	1.5	μA
DUTY AND	FREQUENCY CONTROL					
t _{OFF(min)}	Minimum off time	T _A = 25°C	150	260	400	ns
t _{ON(min)}	Minimum on time	V_{IN} = 17 V, V_{OUT} = 0.6 V, R_{RF} = 39 k Ω , T_A = 25 °C ⁽¹⁾		35		ns
SOFT STA	RT					
		$R_{MODE} = 39 \text{ k}\Omega$		0.7		
	Internal soft-start time from	R_{MODE} = 100 k Ω		1.4		
t _{SS}	V_{OUT} = 0 V to 95% of V_{OUT}	$R_{MODE} = 200 \text{ k}\Omega$		2.8		ms
		$R_{MODE} = 470 \text{ k}\Omega$		5.6		l
INTERNAL	. MOSFETs					



Over recommended free-air temper	ature range, V _{VDD} =	12 V	(unless otherwise noted)
----------------------------------	---------------------------------	------	--------------------------

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
R _{DS(on)H}	High-side MOSFET on-resistance	T _A = 25 °C		5.5		
R _{DS(on)L}	Low-side MOSFET on-resistance	T _A = 25 °C		2.2		mΩ
POWERGO	OOD					
		PG in from lower	92.5%	95%	98.5%	
V_{THPG}	PG threshold	PG in from higher	107.5%	110%	112.5%	
		PG hysteresis	2.5%	5%	7.5%	-
R _{PG}	PG transistor on-resistance		15	30	55	Ω
t _{PGDEL}	PG delay	Delay for PG in	0.8	1	1.2	ms
LOGIC TH	RESHOLD AND SETTING CONDITION	NS				
		Enable	1.8			
V_{EN}	EN Voltage	Disable			0.6	V
I _{EN}	EN Input current	V _{EN} = 5 V			1	μA
		$R_{RF} = 0 \Omega$ to GND, $T_A = 25^{\circ}C^{(2)}$	200	250	300	-
		$R_{RF} = 187 \text{ k}\Omega \text{ to GND, } T_A = 25^{\circ}\text{C}^{(2)}$	250	300	350	
		$R_{RF} = 619 \text{ k}\Omega$, to GND, $T_A = 25^{\circ}\text{C}^{(2)}$	350	400	450	
		R _{RF} = Open, T _A = 25°C ⁽²⁾	450	500	550	
f_{SW}	Switching frequency	$R_{RF} = 866 \text{ k}\Omega \text{ to VREG}, T_A = 25^{\circ}\text{C}^{(2)}$	580	650	720	- kHz -
		$R_{RF} = 309 \text{ k}\Omega \text{ to VREG, } T_A = 25^{\circ}\text{C}^{(2)}$	670	750	820	
		$R_{RF} = 124 \text{ k}\Omega \text{ to VREG, } T_A = 25^{\circ}\text{C}^{(2)}$	770	850	930	
		$R_{RF} = 0 \Omega$ to VREG, $T_A = 25^{\circ}C^{(2)}$	880	970	1070	
PROTECT	ION: CURRENT SENSE	. , ,				
I _{TRIP}	TRIP source current	V _{TRIP} = 1 V, T _A = 25°C	9.4	10	10.6	μA
TC _{ITRIP}	TRIP current temperature coeffficient	On the basis of 25°C ⁽¹⁾		4700		ppm/°C
V _{TRIP}	Current limit threshold setting range	V _{TRIP-GND}	0.4		1.2	V
		V _{TRIP} = 1.2 V	32	37.5	43	.,
V _{OCL}	Current limit threshold	V _{TRIP} = 0.4	7.5	12.5	17.5	mV
		V _{TRIP} = 1.2 V	-160	-150	-140	
V _{OCLN}	Negative current limit threshold	V _{TRIP} = 0.4 V	-58	-50	-42	mV
. ,		Positive	3	15		.,
V _{AZCADJ}	Auto zero cross adjustable range	Negative		-15	-3	mV
PROTECT	ION: UVP and OVP					
V _{OVP}	OVP trip threshold	OVP detect	115%	120%	125%	
t _{OVPDEL}	OVP proprogation delay	VFB delay with 50-mV overdrive		1		μs
V _{UVP}	Output UVP trip threshold	UVP detect	65%	70%	75%	
t _{UVPDEL}	Output UVP proprogation delay		0.8	1	1.2	ms
t _{UVPEN}	Output UVP enable delay	From enable to UVP workable	1.8	2.6	3.2	ms
UVLO	-	1	I			1
	VD=0.19.4.0.4	Wake up	4	4.2	4.33	
V_{UVVREG}	VREG UVLO threshold	Hysteresis		0.25		V
THERMAL	SHUTDOWN	1				1
_		Shutdown temperature ⁽¹⁾		145		
T _{SDN}	Thermal shutdown threshold	Hysteresis ⁽¹⁾		10		°C

⁽¹⁾ Ensured by design. Not production tested.

Product Folder Links: TPS53353

Submit Document Feedback

6

⁽²⁾ Not production tested. Test condition is V_{IN}= 12 V, V_{OUT}= 1.1 V, I_{OUT} = 10 A using application circuit shown in Figure 8-1.

6.6 Typical Characteristics

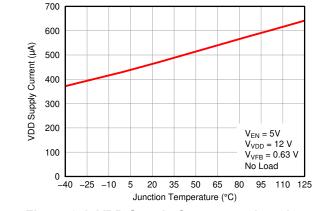


Figure 6-1. VDD Supply Current vs. Junction Temperature

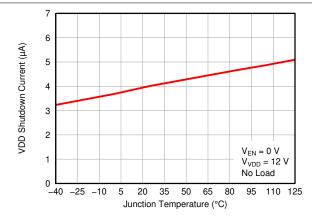


Figure 6-2. VDD Shutdown Current vs. Junction Temperature

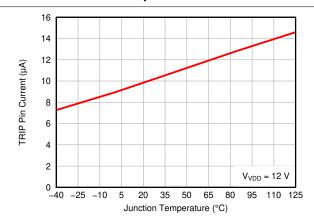


Figure 6-3. TRIP Pin Current vs. Junction Temperature

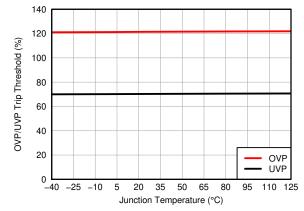


Figure 6-4. OVP/UVP Trip Threshold vs. Junction Temperature

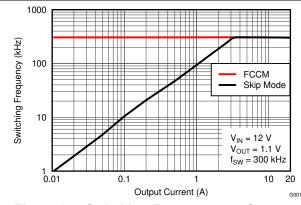


Figure 6-5. Switching Frequency vs. Output Current

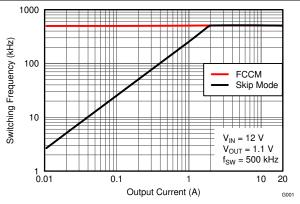
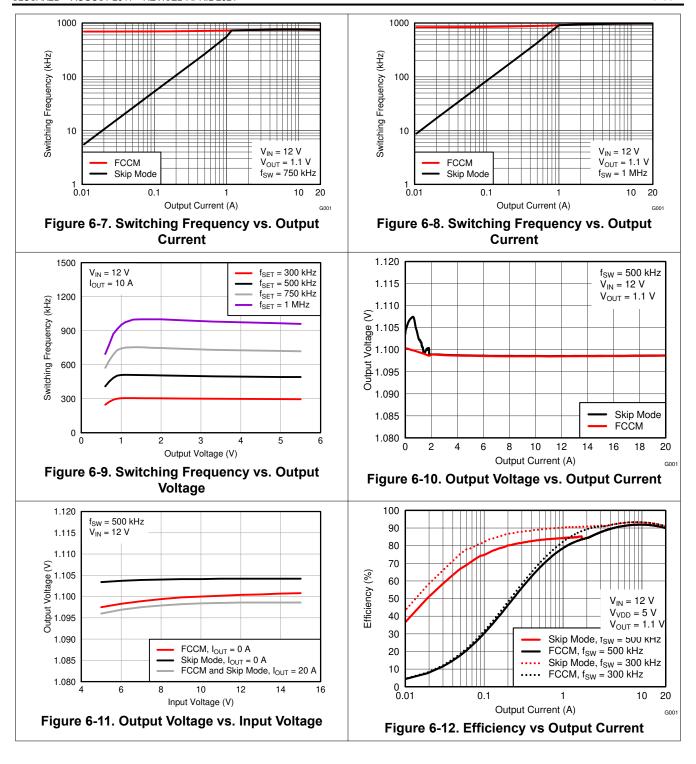
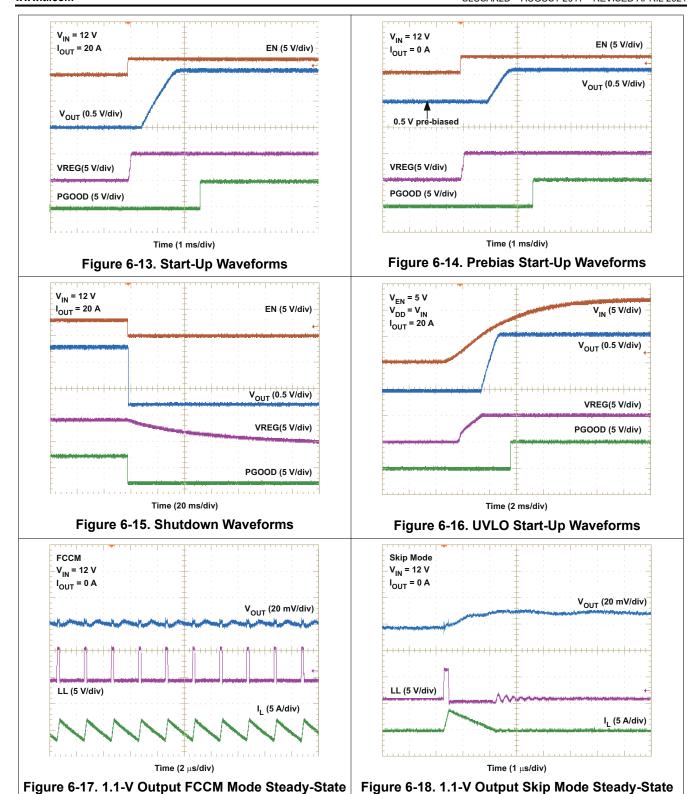


Figure 6-6. Switching Frequency vs. Output Current



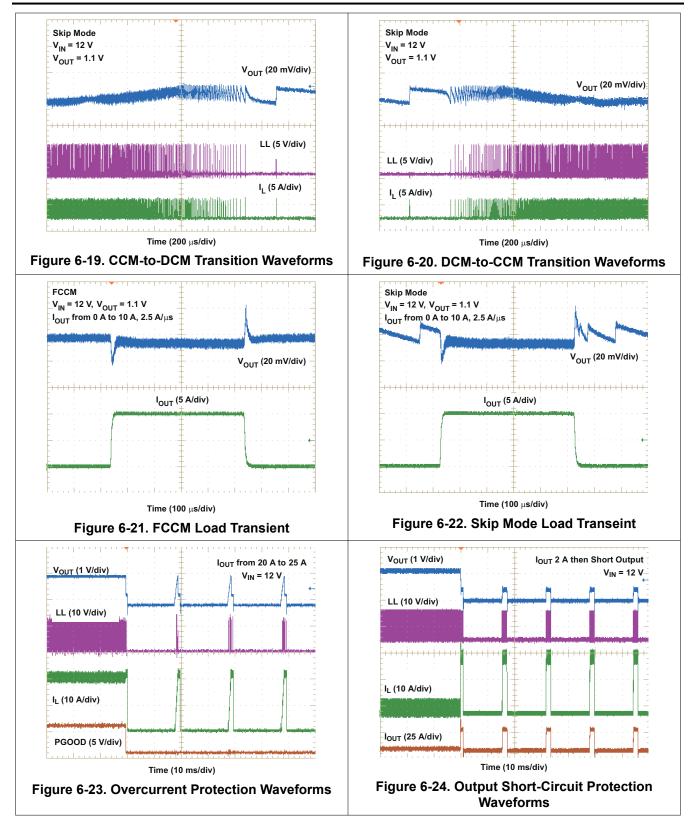




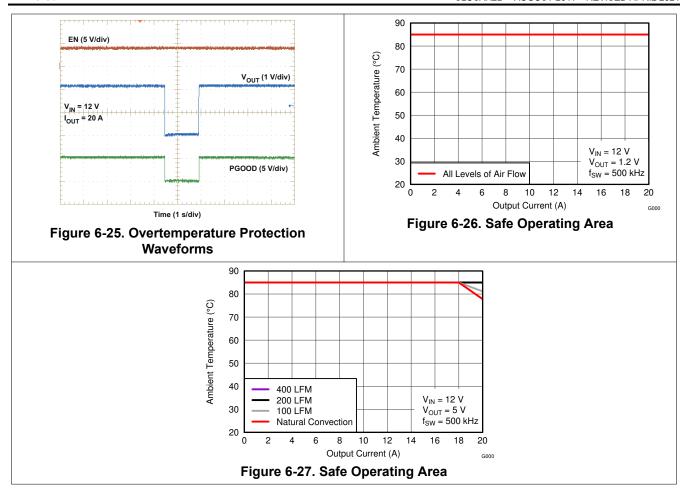
Operation

Operation



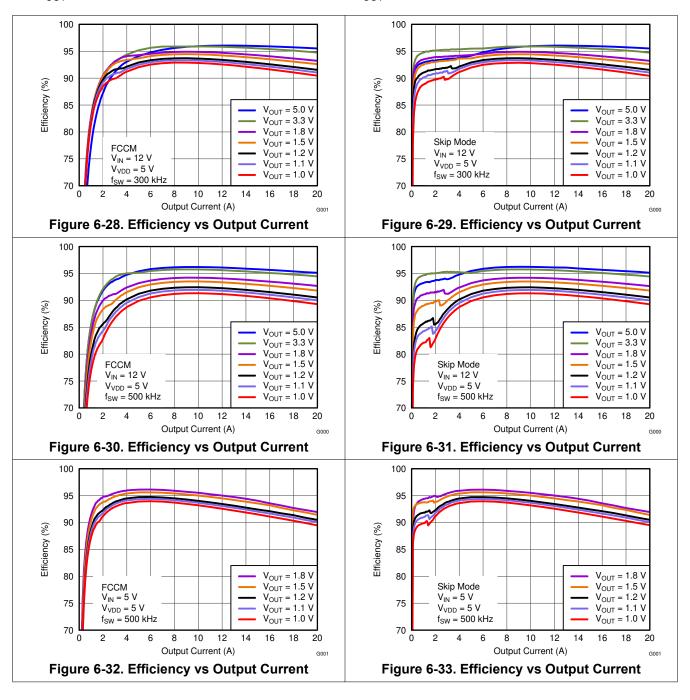








For $V_{OUT} = 5 \text{ V}$, an SC5026-1R0 inductor is used. For $1 \le V_{OUT} \le 3.3 \text{ V}$, a PA0513.441 inductor is used



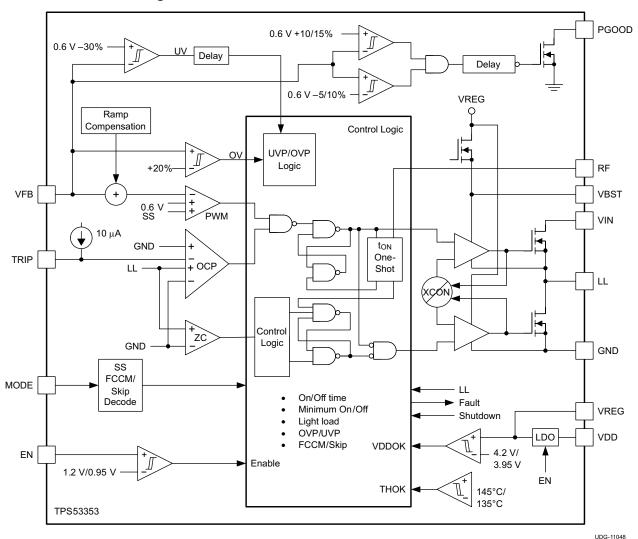
7 Detailed Description

7.1 Overview

The TPS53353 is a high-efficiency, single channel, synchronous buck converter suitable for low output voltage point-of-load applications in computing and similar digital consumer applications. The device features proprietary D-CAP™ mode control combined with an adaptive on-time architecture. This combination is ideal for building modern low duty ratio, ultra-fast load step response DC-DC converters. The output voltage ranges from 0.6 V to 5.5 V. The conversion input voltage range is from 1.5 V up to 15 V and the VDD bias voltage is from 4.5 V to 25 V. The D-CAP™ mode uses the equivalent series resistance (ESR) of the output capacitor(s) to sense the device current . One advantage of this control scheme is that it does not require an external phase compensation network. This allows a simple design with a low external component count. Eight preset switching frequency values can be chosen using a resistor connected from the RF pin to ground or VREG. Adaptive on-time control tracks the preset switching frequency over a wide input and output voltage range while allowing the switching frequency to increase at the step-up of the load.

The TPS53353 has a MODE pin to select between auto-skip mode and forced continuous conduction mode (FCCM) for light load conditions. The MODE pin also sets the selectable soft-start time ranging from 0.7 ms to 5.6 ms as shown in Table 7-3.

7.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

Note

The thresholds in this block diagram are typical values. Refer to the *Section 6.5* table for threshold limits.

7.3 Feature Description

7.3.1 5-V LDO and VREG Start-Up

TPS53353 provides an internal 5V LDO function using input from VDD and output to VREG. The 5V LDO is gated by the EN pin. The LDO starts-up when EN is approximately 1.8V and VDD is approximately 2V. (See Figure 7-1) The LDO outputs its voltage to the VREG pin. The VREG voltage provides the bias voltage for the internal analog circuitry and also provides the supply voltage for the gate drives.

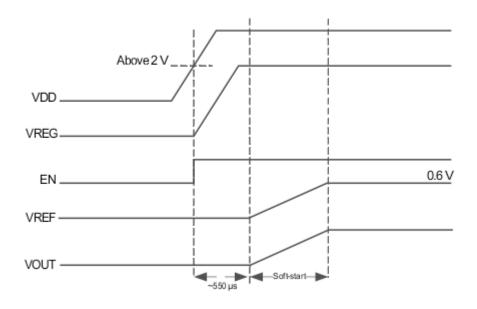


Figure 7-1. Power Up Sequence

7.3.2 Adaptive On-Time D-CAP™ Control and Frequency Selection

The TPS53353 does not have a dedicated oscillator to determine switching frequency. However, the device operates with pseudo-constant frequency by feed-forwarding the input and output voltages into the on-time one-shot timer. The adaptive on-time control adjusts the on-time to be inversely proportional to the input voltage and proportional to the output voltage ($t_{ON} \propto V_{OUT}/V_{IN}$).

This makes the switching frequency fairly constant in steady state conditions over a wide input voltage range. The switching frequency is selectable from eight preset values by a resistor connected between the RF pin and GND or between the RF pin and the VREG pin as shown in Table 7-1. (Maintaining open resistance sets the switching frequency to 500 kHz.)

Table 7-1. Resistor and Switching Frequency

	SISTOR (R _{RF}) NNECTIONS	SWITCHING FREQUENCY
VALUE (kΩ)	CONNECT TO	(f _{SW}) (kHz)
0	GND	250
187	GND	300
619	GND	400

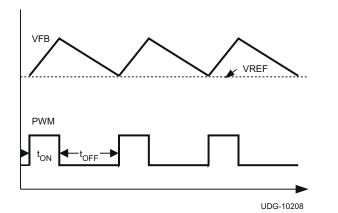
Submit Document Feedback

(continuou)					
	SISTOR (R _{RF}) NNECTIONS	SWITCHING FREQUENCY			
VALUE (kΩ)	CONNECT TO	(f _{SW}) (kHz)			
OPEN	n/a	500			
866	VREG	650			
309	VREG	750			
124	VREG	850			
0	VREG	970			

Table 7-1. Resistor and Switching Frequency (continued)

The off-time is modulated by a PWM comparator. The VFB node voltage (the mid-point of resistor divider) is compared to the internal 0.6-V reference voltage added with a ramp signal. When both signals match, the PWM comparator asserts a set signal to terminate the off time (turn off the low-side MOSFET and turn on high-side MOSFET). The set signal is valid if the inductor current level is below the OCP threshold, otherwise the off time is extended until the current level falls below the threshold.

Figure 7-2 and Figure 7-3 show two on-time control schemes.



VREF

VREF

Compensation
Ramp

UDG-10209

Figure 7-2. On-Time Control Without Ramp Compensation

Figure 7-3. On-Time Control With Ramp Compensation

7.3.3 Ramp Signal

The TPS53353 adds a ramp signal to the 0.6-V reference in order to improve jitter performance. As described in the previous section, the feedback voltage is compared with the reference information to keep the output voltage in regulation. By adding a small ramp signal to the reference, the signal-to-noise ratio at the onset of a new switching cycle is improved. Therefore the operation becomes less jittery and more stable. The ramp signal is controlled to start with –7 mV at the beginning of an on-cycle and becomes 0 mV at the end of an off-cycle in steady state.

During skip mode operation, under discontinuous conduction mode (DCM), the switching frequency is lower than the nominal frequency and the off-time is longer than the off-time in CCM. Because of the longer off-time, the ramp signal extends after crossing 0 mV. However, it is clamped at 3 mV to minimize the DC offset.

7.3.4 Adaptive Zero Crossing

The TPS53353 has an adaptive zero crossing circuit which performs optimization of the zero inductor current detection at skip mode operation. This function pursues ideal low-side MOSFET turning off timing and compensates inherent offset voltage of the Z-C comparator and delay time of the Z-C detection circuit. It prevents SW-node swing-up caused by too late detection and minimizes diode conduction period caused by too early detection. As a result, better light load efficiency is delivered.

7.3.5 Power-Good

The TPS53353 has power-good output that indicates high when switcher output is within the target. The power-good function is activated after soft-start has finished. If the output voltage becomes within +10% and -5% of the target value, internal comparators detect power-good state and the power-good signal becomes high after a 1-ms internal delay. If the output voltage goes outside of +15% or -10% of the target value, the power-good signal becomes low after two microsecond (2- μ s) internal delay. The power-good output is an open drain output and must be pulled up externally.

The power-good MOSFET is powered through the VDD pin. V_{VDD} must be >1 V in order to have a valid power-good logic. It is recommended to pull PGOOD up to VREG (or a voltage divided from VREG) so that the power-good logic is still valid even without VDD supply.

7.3.6 Current Sense, Overcurrent and Short Circuit Protection

TPS53353 has cycle-by-cycle overcurrent limiting control. The inductor current is monitored during the *OFF* state and the controller maintains the *OFF* state during the period in that the inductor current is larger than the overcurrent trip level. In order to provide both good accuracy and cost effective solution, TPS53353 supports temperature compensated MOSFET $R_{DS(on)}$ sensing. The TRIP pin should be connected to GND through the trip voltage setting resistor, R_{TRIP} . The TRIP terminal sources current (I_{TRIP}) which is 10 μ A typically at room temperature, and the trip level is set to the OCL trip voltage V_{TRIP} as shown in Equation 1.

$$V_{TRIP}(mV) = R_{TRIP}(k\Omega) \times I_{TRIP}(\mu A)$$
(1)

The inductor current is monitored by the LL pin. The GND pin is used as the positive current sensing node and the LL pin is used as the negative current sense node. The trip current, I_{TRIP} has 4700ppm/°C temperature slope to compensate the temperature dependency of the R_{DS(on)}.

As the comparison is made during the OFF state, V_{TRIP} sets the valley level of the inductor current. Thus, the load current at the overcurrent threshold, I_{OCP} , can be calculated as shown in Equation 2.

$$I_{OCP} = \frac{V_{TRIP}}{\left(32 \times R_{DS(on)}\right)} + \frac{I_{IND(ripple)}}{2} = \frac{V_{TRIP}}{\left(32 \times R_{DS(on)}\right)} + \frac{1}{2 \times L \times f_{SW}} \times \frac{\left(V_{IN} - V_{OUT}\right) \times V_{OUT}}{V_{IN}} \tag{2}$$

In an overcurrent or short circuit condition, the current to the load exceeds the current to the output capacitor thus the output voltage tends to decrease. Eventually, it crosses the undervoltage protection threshold and shuts down. After a hiccup delay (16 ms with 0.7 ms sort-start), the controller restarts. If the overcurrent condition remains, the procedure is repeated and the device enters hiccup mode.

Hiccup time calculation:

$$t_{HIC(wait)} = (2^n + 257) \times 4 \mu s$$
 (3)

where

• N = 8, 9, 10, or 11 depending on soft start time selection

$$t_{HIC(dly)} = 7 \times (2^n + 257) \times 4 \mu s$$
 (4)

Table 7-2. Hiccup Time Calculation

SELECTED SOFT-START TIME (t _{SS}) (ms)	n	HICCUP WAIT TIME (t _{HIC(wait)}) (ms)	HICCUP DELAY TIME (t _{HIC(dly)}) (ms)
0.7	8	2.052	14.364
1.4	9	3.076	21.532
2.8	10	5.124	35.868
5.6	11	9.22	64.54

7.3.7 Overvoltage and Undervoltage Protection

TPS53353 monitors a resistor divided feedback voltage to detect over and under voltage. When the feedback voltage becomes lower than 70% of the target voltage, the UVP comparator output goes high and an internal UVP delay counter begins counting. After 1ms, TPS53353 latches OFF both high-side and low-side MOSFETs drivers. The controller restarts after a hiccup delay (16 ms with 0.7 ms soft-start). This function is enabled 1.5-ms after the soft-start is completed.

When the feedback voltage becomes higher than 120% of the target voltage, the OVP comparator output goes high and the circuit latches OFF the high-side MOSFET driver and latches ON the low-side MOSFET driver. The output voltage decreases. If the output voltage reaches UV threshold, then both high-side MOSFET and low-side MOSFET driver will be OFF and the device restarts after a hiccup delay. If the OV condition remains, both high-side MOSFET and low-side MOSFET driver remains OFF until the OV condition is removed.

7.3.8 UVLO Protection

The TPS53353 uses VREG undervoltage lockout protection (UVLO). When the VREG voltage is lower than 3.95 V, the device shuts off. When the VREG voltage is higher than 4.2V, the device restarts. This is a non-latch protection.

7.3.9 Thermal Shutdown

TPS53353 monitors the temperature of itself. If the temperature exceeds the threshold value (typically 145°C), TPS53353 is shut off. When the temperature falls about 10°C below the threshold value, the device will turn back on. This is a non-latch protection.

7.4 Device Functional Modes

7.4.1 Small Signal Model

From small-signal loop analysis, a buck converter using D-CAP™ mode can be simplified as shown in Figure 7-4.

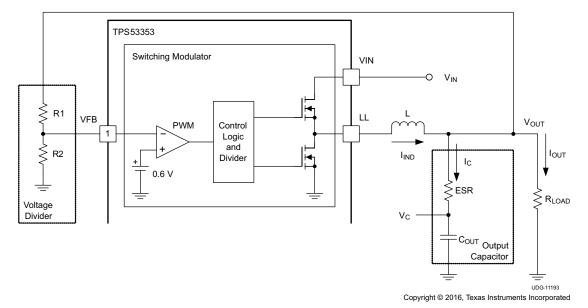


Figure 7-4. Simplified Modulator Model

The output voltage is compared with the internal reference voltage (ramp signal is ignored here for simplicity). The PWM comparator determines the timing to turn on the high-side MOSFET. The gain and speed of the comparator can be assumed high enough to keep the voltage at the beginning of each on cycle substantially constant.

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback



$$H(s) = \frac{1}{s \times ESR \times C_{OUT}}$$
(5)

For loop stability, the 0-dB frequency, f_0 , defined in Equation 6 needs to be lower than 1/4 of the switching frequency.

$$f_0 = \frac{1}{2\pi \times ESR \times C_{OUT}} \le \frac{f_{SW}}{4}$$
(6)

According to Equation 6, the loop stability of D-CAPTM mode modulator is mainly determined by the capacitor's chemistry. For example, specialty polymer capacitors (SP-CAP) have an output capacitance in the order of several 100 μ F and ESR in range of 10 m Ω . These makes f_0 on the order of 100 kHz or less, creating a stable loop. However, ceramic capacitors have an f_0 at more than 700 kHz, and need special care when used with this modulator. An application circuit for ceramic capacitor is described in *Section 8.2.2.2.2*.

7.4.2 Enable, Soft Start, and Mode Selection

When the EN pin voltage rises above the enable threshold voltage (typically 1.2 V), the controller enters its start-up sequence. The internal LDO regulator starts immediately and regulates to 5 V at the VREG pin. The controller then uses the first 250 µs to calibrate the switching frequency setting resistance attached to the RF pin and stores the switching frequency code in internal registers. During this period, the MODE pin also senses the resistance attached to this pin and determines the soft-start time. Switching is inhibited during this phase. In the second phase, an internal DAC starts ramping up the reference voltage from 0 V to 0.6 V. Depending on the MODE pin setting, the ramping up time varies from 0.7 ms to 5.6 ms. Smooth and constant ramp-up of the output voltage is maintained during start-up regardless of load current.

ACTION **SOFT-START TIME (ms) MODE SELECTION** $R_{MODE}(k\Omega)$ 0.7 39 1.4 100 Pulldown to GND Auto-skip 2.8 200 5.6 475 0.7 39 1.4 100 Forced CCM(1) Connect to PGOOD 2.8 200 5.6 475

Table 7-3. Soft-Start and MODE Settings

(1) Device enters FCCM after the PGOOD pin goes high when MODE is connected to PGOOD through the resistor R_{MODE}.

After soft-start begins, the MODE pin becomes the input of an internal comparator which determines auto-skip or FCCM mode operation. If MODE voltage is higher than 1.3 V, the converter enters into FCCM mode. Otherwise it will be in auto-skip mode at light load condition. Typically, when FCCM mode is selected, the MODE pin is connected to PGOOD through the R_{MODE} resistor, so that before PGOOD goes high the converter remains in auto-skip mode.

7.4.3 Auto-Skip Eco-mode™ Light Load Operation

While the MODE pin is pulled low via R_{MODE} , TPS53353 automatically reduces the switching frequency at light load conditions to maintain high efficiency. Detailed operation is described as follows. As the output current decreases from heavy load condition, the inductor current is also reduced and eventually comes to the point that its rippled valley touches zero level, which is the boundary between continuous conduction and discontinuous conduction modes. The synchronous MOSFET is turned off when this zero inductor current is detected. As the load current further decreases, the converter runs into discontinuous conduction mode (DCM). The on-time is kept almost the same as it was in the continuous conduction mode so that it takes longer to discharge the output capacitor with smaller load current to the level of the reference voltage. The transition point to the

light-load operation $I_{OUT(LL)}$ (that is, the threshold between continuous and discontinuous conduction mode) can be calculated as shown in Equation 7.

$$I_{OUT(LL)} = \frac{1}{2 \times L \times f_{SW}} \times \frac{\left(V_{IN} - V_{OUT}\right) \times V_{OUT}}{V_{IN}}$$
(7)

where

• f_{SW} is the PWM switching frequency

Switching frequency versus output current in the light load condition is a function of L, V_{IN} , and V_{OUT} , but it decreases almost proportionally to the output current from the $I_{OUT(LL)}$ given in Equation 7. For example, it is 60 kHz at $I_{OUT(LL)}$ /5 if the frequency setting is 300 kHz.

7.4.4 Forced Continuous Conduction Mode

When the MODE pin is tied to PGOOD through a resistor, the controller keeps continuous conduction mode (CCM) in light load condition. In this mode, switching frequency is kept almost constant over the entire load range which is suitable for applications need tight control of the switching frequency at a cost of lower efficiency.

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TPS53353 is a high-efficiency, single channel, synchronous buck converter suitable for low output voltage point-of-load applications in computing and similar digital consumer applications. The device features proprietary D-CAP mode control combined with an adaptive on-time architecture. This combination is ideal for building modern low duty ratio, ultra-fast load step response DC-DC converters. The output voltage ranges from 0.6 V to 5.5 V. The conversion input voltage range is from 1.5 V up to 15 V and the VDD bias voltage is from 4.5 V to 25 V. The D-CAP mode uses the equivalent series resistance (ESR) of the output capacitor(s) to sense the device current. One advantage of this control scheme is that it does not require an external phase compensation network. This allows a simple design with a low external component count. Eight preset switching frequency values can be chosen using a resistor connected from the RF pin to ground or VREG. Adaptive on-time control tracks the preset switching frequency over a wide input and output voltage range while allowing the switching frequency to increase at the step-up of the load.

8.2 Typical Applications

8.2.1 Typical Application Circuit Diagram

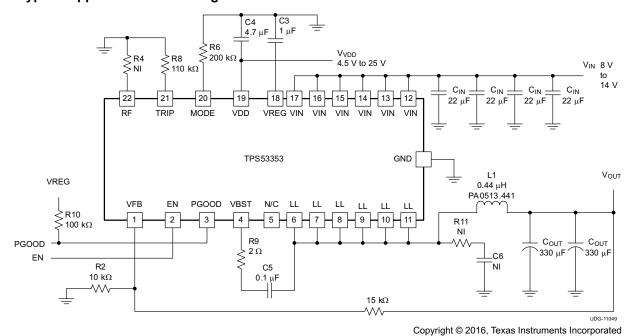


Figure 8-1. Typical Application Circuit Diagram

Product Folder Links: TPS53353



8.2.1.1 Design Requirements

Table 8-1. Design Parameters

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT C	HARACTERISTICS			•		
V _{IN}	Voltage range		8	12	14	V
	Maximum Input current	V _{IN} = 8 V, I _{OUT} = 20 A		4.1		Α
I _{MAX}	No load input current	V _{IN} = 14 V, I _{OUT} = 0 A with auto-skip mode		1		mA
OUTPUT	CHARACTERISTICS					
	Output voltage			1.5		V
V _{OUT}		Line regulation, 8 V ≤ V _{IN} ≤ 15 V				
V OU1	Output voltage regulation	Load regulation, V_{IN} = 12 V, 0 A \leq I _{OUT} \leq 20 A with FCCM 0.2%				
V _{RIPPLE}	Output voltage ripple	V _{IN} = 12 V, I _{OUT} = 20 A with FCCM		20		mV _{PP}
I _{LOAD}	Output load current		0		20	Α
I _{OCP}	Output overcurrent threshold			26		А
t _{SS}	Soft-start time			1.4		ms
SYSTEM	S CHARACTERISTICS					1
f _{SW}	Switching frequency			500		kHz
	Peak efficiency	V _{IN} = 12 V, V _{OUT} = 1.1 V, I _{OUT} = 10 A		91.87%		
η	Full load efficiency	V _{IN} = 12 V, V _{OUT} = 1.1 V, I _{OUT} = 20 A		91.38%		
T _A	Operating temperature			25		°C

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 External Component Selection

Refer to Section 8.2.2.2.2 for guidelines for this design with all ceramic output capacitors.

The external components selection is a simple process when using organic semiconductors or special polymer output capacitors.

1. SELECT OPERATION MODE AND SOFT-START TIME

Select operation mode and soft-start time using Table 7-3.

2. SELECT SWITCHING FREQUENCY

Select the switching frequency from 250 kHz to 1 MHz using Table 7-1.

3. CHOOSE THE INDUCTOR

The inductance value should be determined to give the ripple current of approximately 1/4 to 1/2 of maximum output current. Larger ripple current increases output ripple voltage and improves signal-to-noise ratio and helps ensure stable operation, but increases inductor core loss. Using 1/3 ripple current to maximum output current ratio, the inductance can be determined by Equation 8.

$$L = \frac{1}{I_{IND(ripple)} \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}} = \frac{3}{I_{OUT(max)} \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}} \tag{8}$$

The inductor requires a low DCR to achieve good efficiency. It also requires enough room above peak inductor current before saturation. The peak inductor current can be estimated in Equation 9.



$$I_{IND(peak)} = \frac{V_{TRIP}}{32 \times R_{DS(on)}} + \frac{1}{L \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}}$$
(9)

4. CHOOSE THE OUTPUT CAPACITORS

When organic semiconductor capacitors or specialty polymer capacitors are used, for loop stability, capacitance and ESR should satisfy Equation 6. For jitter performance, Equation 10 is a good starting point to determine ESR.

$$ESR = \frac{V_{OUT} \times 10 \,\text{mV} \times (1 - D)}{0.6 \,\text{V} \times I_{\text{IND(ripple)}}} = \frac{10 \,\text{mV} \times L \times f_{\text{SW}}}{0.6 \,\text{V}} = \frac{L \times f_{\text{SW}}}{60} \left(\Omega\right) \tag{10}$$

where

- D is the duty factor.
- The required output ripple slope is approximately 10 mV per t_{SW} (switching period) in terms of VFB terminal voltage.

5. DETERMINE THE VALUE OF R1 AND R2

The output voltage is programmed by the voltage-divider resistor, R1 and R2 shown in Figure 7-4. R1 is connected between VFB pin and the output, and R2 is connected between the VFB pin and GND. Recommended R2 value is from 1 k Ω to 20 k Ω . Determine R1 using Equation 11.

$$R1 = \frac{V_{OUT} - \frac{I_{IND(ripple)} \times ESR}{2} - 0.6}{0.6} \times R2$$
(11)

6. CHOOSE THE OVERCURRENT SETTING RESISTOR

The overcurrent setting resistor, R_{TRIP}, can be determined by Equation 12.

$$R_{TRIP}(k\Omega) = \frac{\left(I_{OCP} - \left(\frac{1}{2 \times L \times f_{SW}}\right) \times \frac{\left(V_{IN} - V_{OUT}\right) \times V_{OUT}}{V_{IN}}\right) \times 32 \times R_{DS(on)}(m\Omega)}{I_{TRIP}(\mu A)}$$
(12)

where

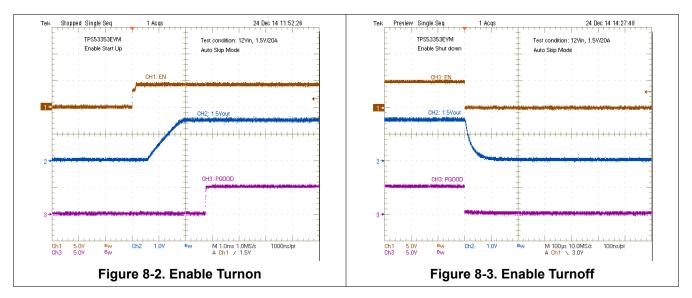
- I_{TRIP} is the TRIP pin sourcing current (10 μA).
- R_{DS(on)} is the thermally compensated on-time resistance value of the low-side MOSFET.

Use an $R_{DS(on)}$ value of 1.6 m Ω for an overcurrent level of approximately 20 A. Use an $R_{DS(on)}$ value of 1.7 m Ω for overcurrent level of approximately 10 A.

Submit Document Feedback

Copyright © 2021 Texas Instruments Incorporated

8.2.1.3 Application Curves



8.2.2 Typical Application Circuit Diagram With Ceramic Output Capacitors

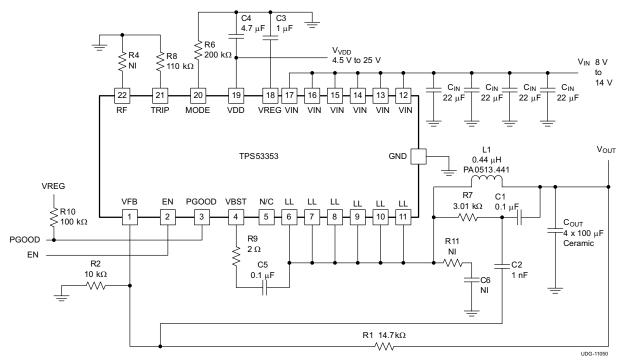


Figure 8-4. Typical Application Circuit Diagram With Ceramic Output Capacitors



8.2.2.1 Design Requirements

Table 8-2. Design Parameters

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT C	HARACTERISTICS					1
V _{IN}	Voltage range		8	12	14	V
	Maximum Input current	V _{IN} = 8 V, I _{OUT} = 20 A			А	
I _{MAX}	No load input current	V _{IN} = 14 V, I _{OUT} = 0 A with auto-skip mode		1		mA
OUTPUT	CHARACTERISTICS					
	Output voltage			1.5		V
V _{OUT}		Line regulation, 8 V ≤ V _{IN} ≤ 15 V				
¥001	Output voltage regulation	Load regulation, V_{IN} = 12 V, 0 A \leq I _{OUT} \leq 20 A with FCCM		0.2%		
V _{RIPPLE}	Output voltage ripple	V _{IN} = 12 V, I _{OUT} = 20 A with FCCM		20		mV _{PP}
I _{LOAD}	Output load current		0		20	А
I _{OCP}	Output overcurrent threshold			26		А
t _{SS}	Soft-start time			1.4		ms
SYSTEM	S CHARACTERISTICS					
f _{SW}	Switching frequency			500		kHz
-	Peak efficiency	V _{IN} = 12 V, V _{OUT} = 1.1 V, I _{OUT} = 10 A		91.87%		
η	Full load efficiency	V _{IN} = 12 V, V _{OUT} = 1.1 V, I _{OUT} = 20 A		91.38%		
T _A	Operating temperature			25		°C

8.2.2.2 Detailed Design Procedure

8.2.2.2.1 External Component Selection

Refer to Section 8.2.2.2 for guidelines for this design with all ceramic output capacitors.

The external components selection is a simple process when using organic semiconductors or special polymer output capacitors.

1. Select Operation Mode and Soft-Start Time

Select operation mode and soft-start time using Table 7-3.

2. Select Switching Frequency

Select the switching frequency from 250 kHz to 1 MHz using Table 7-1.

3. Choose The Inductor

The inductance value should be determined to give the ripple current of approximately 1/4 to 1/2 of maximum output current. Larger ripple current increases output ripple voltage and improves signal-to-noise ratio and helps ensure stable operation, but increases inductor core loss. Using 1/3 ripple current to maximum output current ratio, the inductance can be determined by Equation 8.

$$L = \frac{1}{I_{IND(ripple)} \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}} = \frac{3}{I_{OUT(max)} \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}}$$
(13)

The inductor requires a low DCR to achieve good efficiency. It also requires enough room above peak inductor current before saturation. The peak inductor current can be estimated in Equation 9.

$$I_{IND(peak)} = \frac{V_{TRIP}}{32 \times R_{DS(on)}} + \frac{1}{L \times f_{SW}} \times \frac{\left(V_{IN(max)} - V_{OUT}\right) \times V_{OUT}}{V_{IN(max)}}$$
(14)

4. External Component Selection with All Ceramic Output Capacitors

Refer to Section 8.2.2.2.2 to select external components because ceramic output capacitors are used in this design.

5. Choose the Overcurrent Setting Resistor

The overcurrent setting resistor, R_{TRIP}, can be determined by Equation 15.

$$R_{TRIP}(k\Omega) = \frac{\left(I_{OCP} - \left(\frac{1}{2 \times L \times f_{SW}}\right) \times \frac{\left(V_{IN} - V_{OUT}\right) \times V_{OUT}}{V_{IN}}\right) \times 32 \times R_{DS(on)}(m\Omega)}{I_{TRIP}(\mu A)}$$
(15)

where

- I_{TRIP} is the TRIP pin sourcing current (10 μA).
- R_{DS(on)} is the thermally compensated on-time resistance value of the low-side MOSFET.

Use an $R_{DS(on)}$ value of 1.6 m Ω for an overcurrent level of approximately 20 A. Use an $R_{DS(on)}$ value of 1.7 m Ω for overcurrent level of approximately 10 A.

6. BST Resistor Selection

The recommended BST resistor value is 2 Ω and anything larger than 5.1 Ω is not recommended. Note that when the gate drive turns on, the voltage on the boot-strap capacitor splits between the internal pull-up resistance and the boot-strap resistance, with the internal circuits only seeing the portion across the internal pull-up resistance. Therefore, when the external resistor gets larger than the pull-up resistance, it crashes the head-room of the SW to BOOT logic, which can cause logic issues with the high-side gate driver.

8.2.2.2.2 External Component Selection Using All Ceramic Output Capacitors

When a ceramic output capacitor is used, the stability criteria in Equation 6 cannot be satisfied. The ripple injection approach as shown in Figure 8-4 is implemented to increase the ripple on the VFB pin and make the system stable. In addition to the selections made using Steps 1 through Step 5 in Section 8.2.2.2.1, the ripple injection components must be selected. The C2 value can be fixed at 1 nF. The value of C1 can be selected from 10 nF to 200 nF.

$$\frac{L \times C_{OUT}}{R7 \times C1} > N \times \frac{t_{ON}}{2}$$
 (16)

where

N is the coefficient to account for L and C_{OUT} variation.

N is also used to provide enough margin for stability. It is recommended N = 2 for $V_{OUT} \le 1.8$ V and N = 4 for $V_{OUT} \ge 3.3$ V or when L ≤ 250 nH. The higher V_{OUT} needs a higher N value because the effective output capacitance is reduced significantly with higher DC bias. For example, a 6.3-V, 22- μ F ceramic capacitor may have only 8 μ F of effective capacitance when biased at 5 V.

Because the VFB pin voltage is regulated at the valley, the increased ripple on the VFB pin causes the increase of the VFB DC value. The AC ripple coupled to the VFB pin has two components, one coupled from SW node and the other coupled from the VOUT pin and they can be calculated using Equation 17 and Equation 18 when neglecting the output voltage ripple caused by equivalent series inductance (ESL).

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback



$$V_{INJ_SW} = \frac{V_{IN} - V_{OUT}}{R7 \times C1} \times \frac{D}{f_{SW}}$$
(17)

$$V_{INJ_OUT} = ESR \times I_{IND(ripple)} + \frac{I_{IND(ripple)}}{8 \times C_{OUT} \times f_{SW}}$$
(18)

It is recommended that V_{INJ_SW} to be less than 50 mV and V_{INJ_TOTAL} to be less than 60mV. If the calculated V_{INJ_SW} is higher than 50 mV, then other parameters must be adjusted to reduce it. For example, C_{OUT} can be increased to satisfy Equation 16 with a higher R7 value, thereby reducing V_{INJ_SW} . Use Equation 19 to calculate C_{OUT} capacitance needed. For a more holistic calculation, please reference the TPS53353 calculator on ti.com

$$C_{OUT} = \frac{V_{IN(MAX)} - V_{OUT}}{2 \times L \times V_{INJ(MAX)}} \times N \times t_{ON}$$
(19)

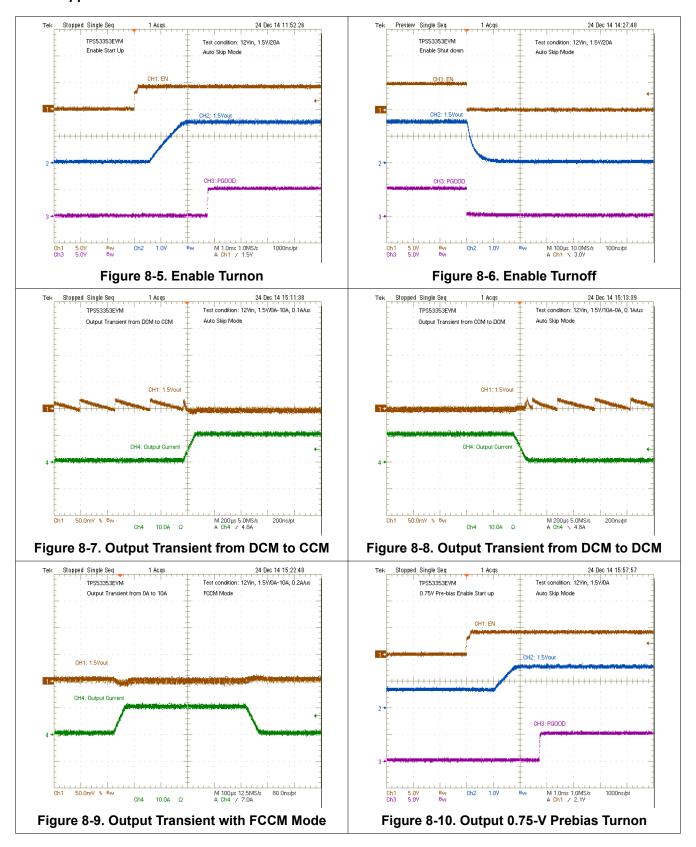
The DC voltage at the VFB pin can be calculated by Equation 20:

$$V_{VFB} = 0.6 + \frac{V_{INJ_SW} + V_{INJ_OUT}}{2}$$
 (20)

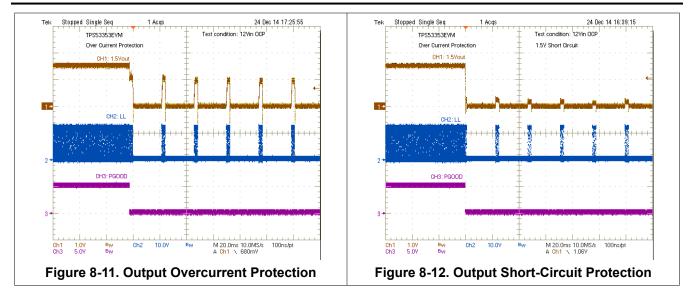
And the resistor divider value can be determined by Equation 21:

$$R1 = \frac{V_{OUT} - V_{VFB}}{V_{VFB}} \times R2 \tag{21}$$

8.2.2.3 Application Curves









9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 1.5 V to 22 V (4.5 V to 25 V biased). This input supply must be well regulated. Proper bypassing of input supplies and internal regulators is also critical for noise performance, as is PCB layout and grounding scheme. See the recommendations in *Section 10*.

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback



10 Layout

10.1 Layout Guidelines

Certain points must be considered before starting a layout work using the TPS53353.

- The power components (including input/output capacitors, inductor and TPS53353) should be placed on one side of the PCB (solder side). At least one inner plane should be inserted, connected to ground, in order to shield and isolate the small signal traces from noisy power lines.
- All sensitive analog traces and components such as VFB, PGOOD, TRIP, MODE and RF should be placed away from high-voltage switching nodes such as LL, VBST to avoid coupling. Use internal layer(s) as ground plane(s) and shield feedback trace from power traces and components.
- Place the VIN decoupling capacitors as close to the VIN and PGND pins as possible to minimize the input AC current loop.
- Because the TPS53353 controls output voltage referring to voltage across VOUT capacitor, the top-side
 resistor of the voltage divider should be connected to the positive node of the VOUT capacitor. The GND of
 the bottom side resistor should be connected to the GND pad of the device. The trace from these resistors to
 the VFB pin should be short and thin.
- Place the frequency setting resistor (R_F), OCP setting resistor (R_{TRIP}) and mode setting resistor (R_{MODE}) as close to the device as possible. Use the common GND via to connect them to GND plane if applicable.
- Place the VDD and VREG decoupling capacitors as close to the device as possible. Ensure to provide GND vias for each decoupling capacitor and make the loop as small as possible.
- The PCB trace defined as switch node, which connects the LL pins and high-voltage side of the inductor, should be as short and wide as possible.
- Connect the ripple injection V_{OUT} signal (V_{OUT} side of the C1 capacitor in Figure 8-4) from the terminal of ceramic output capacitor. The AC coupling capacitor (C2 in Figure 8-4) should be placed near the device, and R7 and C1 can be placed near the power stage.
- Use separated vias or trace to connect LL node to snubber, boot strap capacitor and ripple injection resistor.
 Do not combine these connections.

Product Folder Links: TPS53353



10.2 Layout Example

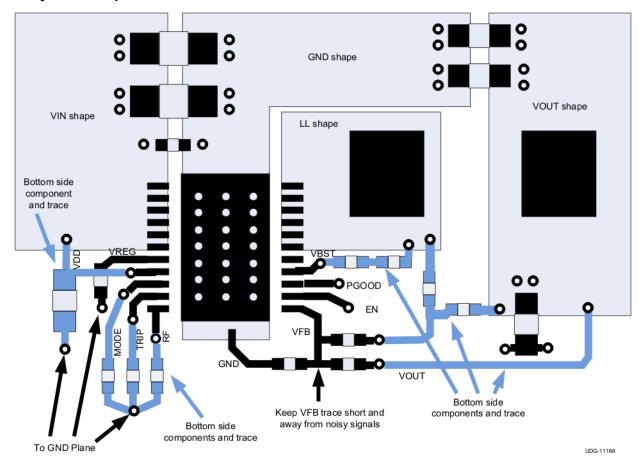


Figure 10-1. Layout Recommendation



11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

11.4 Trademarks

Eco-mode[™], NexFET[™], and PowerPAD[™] are trademarks of TI. SWIFT[™] and TI E2E[™] are trademarks of Texas Instruments. All trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Submit Document Feedback

Copyright © 2021 Texas Instruments Incorporated

www.ti.com 19-Jun-2021

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS53353DQPR	ACTIVE	LSON-CLIP	DQP	22	2500	RoHS-Exempt & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	53353DQP	Samples
TPS53353DQPT	ACTIVE	LSON-CLIP	DQP	22	250	RoHS-Exempt & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	53353DQP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



PACKAGE OPTION ADDENDUM

www.ti.com 19-Jun-2021

www.ti.com 24-Nov-2021

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

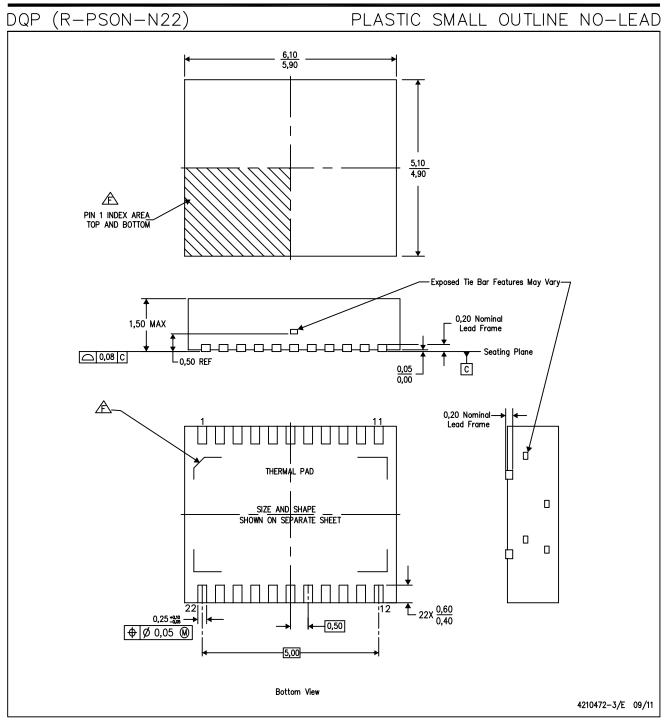
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS53353DQPR	LSON- CLIP	DQP	22	2500	330.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1
TPS53353DQPR	LSON- CLIP	DQP	22	2500	330.0	15.4	5.3	6.3	1.8	8.0	12.0	Q1
TPS53353DQPT	LSON- CLIP	DQP	22	250	180.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1
TPS53353DQPT	LSON- CLIP	DQP	22	250	330.0	15.4	5.3	6.3	1.8	8.0	12.0	Q1

www.ti.com 24-Nov-2021



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS53353DQPR	LSON-CLIP	DQP	22	2500	367.0	367.0	35.0
TPS53353DQPR	LSON-CLIP	DQP	22	2500	336.6	336.6	41.3
TPS53353DQPT	LSON-CLIP	DQP	22	250	210.0	185.0	35.0
TPS53353DQPT	LSON-CLIP	DQP	22	250	336.6	336.6	41.3



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.

 The Pin 1 identifiers are either a molded, marked, or metal feature.



DQP (R-PSON-N22)

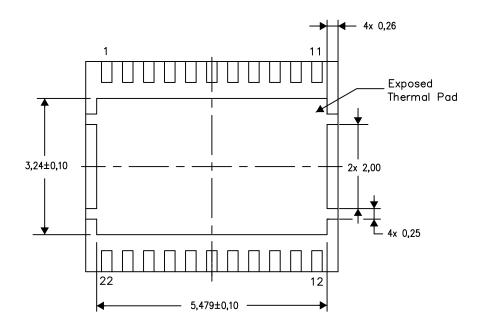
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

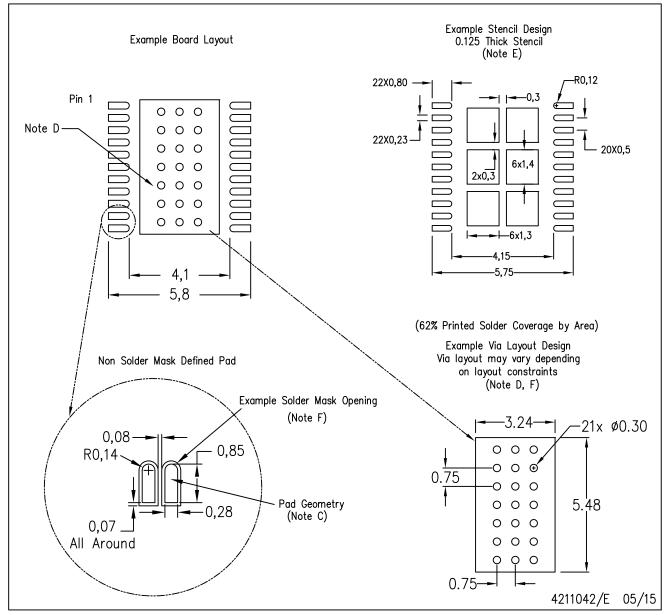
4211024-3/H 08/15

NOTE: All linear dimensions are in millimeters



DQP (R-PSON-N22)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated